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# 2SA1350

Silicon PNP Epitaxial

# HITACHI

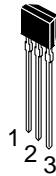
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## Application

- Low frequency low noise amplifier
- HF amplifier

## Outline

SPAK



1. Emitter
2. Collector
3. Base

## 2SA1350

### Absolute Maximum Ratings (Ta = 25°C)

| Item                         | Symbol    | Ratings     | Unit |
|------------------------------|-----------|-------------|------|
| Collector to base voltage    | $V_{CBO}$ | -40         | V    |
| Collector to emitter voltage | $V_{CEO}$ | -30         | V    |
| Emitter to base voltage      | $V_{EBO}$ | -5          | V    |
| Collector current            | $I_C$     | -100        | mA   |
| Collector power dissipation  | $P_C$     | 300         | mW   |
| Junction temperature         | $T_j$     | 150         | °C   |
| Storage temperature          | $T_{stg}$ | -55 to +150 | °C   |

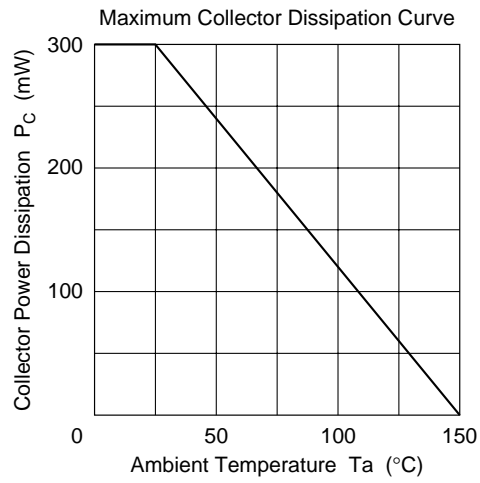
### Electrical Characteristics (Ta = 25°C)

| Item                                    | Symbol        | Min | Typ | Max   | Unit    | Test conditions  |
|---|---------------|-----|-----|-------|---------|--|
| Collector to base breakdown voltage     | $V_{(BR)CBO}$ | -40 | —   | —     | V       | $I_C = -10 \mu A, I_E = 0$   |
| Collector to emitter breakdown voltage  | $V_{(BR)CEO}$ | -30 | —   | —     | V       | $I_C = -1 \text{ mA}, R_{BE} = \infty$   |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$ | -5  | —   | —     | V       | $I_E = -10 \mu A, I_C = 0$   |
| Collector cutoff current                | $I_{CBO}$     | —   | —   | -0.5  | $\mu A$ | $V_{CB} = -18 \text{ V}, I_E = 0$  |
| Emitter cutoff current                  | $I_{EBO}$     | —   | —   | -0.5  | $\mu A$ | $V_{EB} = -2 \text{ V}, I_C = 0$   |
| DC current transfer ratio               | $h_{FE}^{*1}$ | 100 | —   | 500   |         | $V_{CE} = -12 \text{ V}, I_C = -2 \text{ mA}$  |
| Base to emitter voltage                 | $V_{BE}$      | —   | —   | -0.75 | V       | $V_{CE} = -12 \text{ V}, I_C = -2 \text{ mA}$  |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | —   | —   | -0.2  | V       | $I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$  |
| Gain bandwidth product                  | $f_T$         | —   | 200 | —     | MHz     | $V_{CE} = -12 \text{ V}, I_C = -2 \text{ mA}$  |
| Collector output capacitance            | $C_{ob}$      | —   | —   | 4.5   | pF      | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$   |
| Noise figure                            | NF            | —   | 1.0 | 5.0   | dB      | $V_{CE} = -6 \text{ V}, I_C = -0.1 \text{ mA}$<br>$R_g = 1 \text{ k}\Omega, f = 1 \text{ kHz}$ |

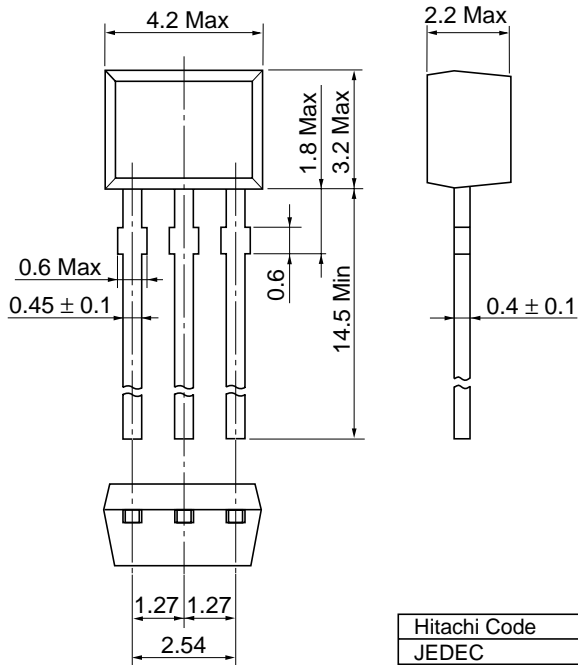
Note: 1. The 2SA1350 is grouped by  $h_{FE}$  as follows.

| B          | C          | D          |
|------------|------------|------------|
| 100 to 200 | 160 to 320 | 250 to 500 |

See characteristic curves of 2SA1031.



Unit: mm



|                          |        |
|--------------------------|--------|
| Hitachi Code             | SPAK   |
| JEDEC                    | —      |
| EIAJ                     | —      |
| Weight (reference value) | 0.10 g |

## Cautions

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## Hitachi, Ltd.

Semiconductor & Integrated Circuits.  
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan  
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL North America : <http://semiconductor.hitachi.com/>  
Europe : <http://www.hitachi-eu.com/hel/ecg>  
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## For further information write to:

Hitachi Semiconductor  
(America) Inc.  
179 East Tasman Drive,  
San Jose, CA 95134  
Tel: <1> (408) 433-1990  
Fax: <1> (408) 433-0223

Hitachi Europe GmbH  
Electronic components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.  
Electronic Components Group.  
Whitebrook Park  
Lower Cookham Road  
Maidenhead  
Berkshire SL6 8YA, United Kingdom  
Tel: <44> (1628) 585000  
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.  
16 Collyer Quay #20-00  
Hitachi Tower  
Singapore 049318  
Tel: 535-2100  
Fax: 535-1533

Hitachi Asia Ltd.  
Taipei Branch Office  
3F, Hung Kuo Building, No.167,  
Tun-Hwa North Road, Taipei (105)  
Tel: <886> (2) 2718-3666  
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower, World Finance Centre,  
Harbour City, Canton Road, Tsim Sha Tsui,  
Kowloon, Hong Kong  
Tel: <852> (2) 735 9218  
Fax: <852> (2) 730 0281  
Telex: 40815 HITEC HX

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